Dual, 200mA Output, Low Noise, High PSRR Low-Dropout Linear Regulators

FEATURES

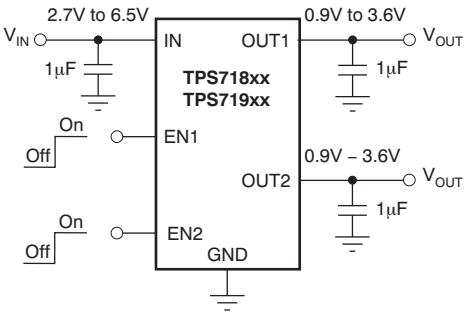
- **Dual, 200mA High-Performance LDOs**
- **Low Total Quiescent Current: 90μA with Both LDOs Enabled**
- **Low Noise: 70μV_{RMS}/V**
- **Active Output Pulldown (TPS719xx)**
- **Independent Enables for Each LDO**
- **PSRR: 65dB at 1kHz, 45dB at 1MHz**
- **Available in Multiple Fixed-Output Voltage Combinations from 0.9V to 3.6V Using Innovative Factory EEPROM Programming**
- **Fast Start-Up Time: 160μs**
- **Over-Current, Over-Temperature and Under-Voltage Protection**
- **Low Dropout: 230mV at 200mA**
- **Stable with 1μF Ceramic Output Capacitor**
- **Available in 2mm × 2mm SON-6 and 6-Ball WCSP Packages**

APPLICATIONS

- **Digital Cameras and Camera Modules**
- **Cellular Camera and TV Phones**
- **Wireless LAN, Bluetooth®**
- **Handheld Products**

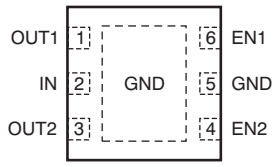
DESCRIPTION

The TPS718xx and TPS719xx families of low-dropout (LDO) regulators offer a high power-supply rejection ratio (PSRR), low noise, fast start-up, and excellent line and load transient responses while consuming a very low 90μA (typical) at no load ground current with both LDOs enabled. The TPS719xx also provides an active pulldown circuit to quickly discharge output loads. The TPS718xx and TPS719xx are stable with ceramic capacitors and use an advanced BiCMOS fabrication process to yield a typical dropout voltage of 230mV at 200mA output loads. The TPS718xx and TPS719xx also use a precision voltage reference and feedback loop to achieve 3% overall accuracy over all load, line, process, and temperature variations. Both families of devices are fully specified from T_J = –40°C to +125°C and are offered in 2mm × 2mm SON-6 and 6-ball Wafer Chip-Scale (WCSP) packages that are ideal for applications such as mobile handsets and WLAN that require good thermal dissipation while maintaining a very small footprint.

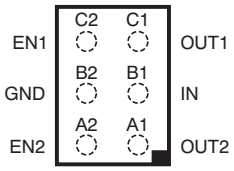


Typical Application Circuit

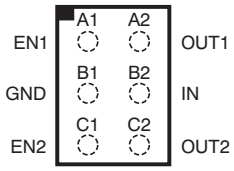
TPS718xx, TPS719xx
DRV Package
2mm x 2mm SON-6
(Top View)



TPS718xx, TPS719xx
YZC Package
6-BALL WCSP
(Top View)



TPS718Axx, TPS719Axx
YZC Package
6-BALL WCSP
(Top View)



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

ORDERING INFORMATION(1)

PRODUCT	V_{OUT}(2)(3)
TPS718***xx-yywwwz*** TPS718A***xx-yywwwz*** TPS719***xx-yywwwz*** TPS719A***xx-yywwwz***	**A** denotes device with rotated pin 1 orientation of wafer-chipscale package. **XX** is nominal output voltage for LDO1 (for example, 28 = 2.8V). **YY** is nominal output voltage for LDO2. **WWW** is package designator. **Z** is tape and reel quantity (R = 3000, T = 250).
Examples: TPS71918–285DRVR TPS719185-33DRVR	**XX** = 18 = 1.8V, **YYY** = 285 = 2.85V **XXX** = 185 = 1.85V, **YY** = 33 = 3.3V **DRV** = 2mm x 2mm SON package **Z** = R = 3000 piece reel

(1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.
(2) Both outputs are programmable from 0.9V to 3.6V in 50mV increments.
(3) Output voltages from 0.9V to 3.6V in 50mV increments are available through the use of innovative factory EEPROM programming; minimum order quantities may apply. Contact factory for details and availability.

ABSOLUTE MAXIMUM RATINGS(1)

Over operating temperature range (unless otherwise noted). All voltages are with respect to GND.

PARAMETER	TPS718xx, TPS719xx	UNIT
Input voltage range, V_{IN}	–0.3 to +7.0	V
Enable voltage range, V_{EN1} and V_{EN2}	–0.3 to V_{IN} + 0.3V	V
Output voltage range, V_{OUT}	–0.3 to +7.0	V
Peak output current	Internally limited	
Output short-circuit duration	Indefinite	
Junction temperature range, T_J	–55 to +150	°C
Storage temperature range , T_{STG}	–55 to +150	°C
Total continuous power dissipation, P_{DISS}	See Dissipation Ratings Table	
ESD rating, HBM	2	kV
ESD rating, CDM	500	V

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

DISSIPATION RATINGS

BOARD	PACKAGE	$R_{\theta JC}$	$R_{\theta JA}$	DERATING FACTOR ABOVE T_A = +25°C	T_A < +25°C	T_A = +70°C	T_A = +85°C
High-K(1)	DRV	20°C/W	95°C/W	10.53mW/°C	1053mW	579mW	421mW
High-K(1)	YZC	27°C/W	190°C/W	5.3mW/°C	530mW	295mW	215mW

(1) The JEDEC high-K (2s2p) board used to derive this data was a 3in × 3in, multilayer board with 1-ounce internal power and ground planes and 2-ounce copper traces on top and bottom of the board.

ELECTRICAL CHARACTERISTICS

Over operating temperature range (T_J = –40°C to +125°C), V_{IN} = $V_{OUT(TYP)}$ + 0.5V or 2.7V, whichever is greater; I_{OUT} = 0.5mA, V_{EN1} = V_{EN2} = V_{IN}, C_{OUT} = 1.0µF, unless otherwise noted. Typical values are at T_J = +25°C.

PARAMETER			TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{IN}	Input voltage range(1)			2.7		6.5	V
V_{OUT1}, V_{OUT2}	Output voltage range			0.9		3.6	V
V_{OUT1}, V_{OUT2}	Output accuracy	Nominal	T_J = +25°C		±2.5		mV
		Over V_{IN}, I_{OUT}, Temp	V_{OUT} + 0.5V ≤ V_{IN} ≤ 6.5V 0mA ≤ I_{OUT} ≤ 200mA	–3.0		+3.0	%
$\Delta V_{OUT}/\Delta V_{IN}$	Line regulation		$V_{OUT(NOM)}$ + 0.5V ≤ V_{IN} ≤ 6.5V, I_{OUT} = 5mA		130		µV/V
$\Delta V_{OUT}/\Delta I_{OUT}$	Load regulation		0mA ≤ I_{OUT} ≤ 200mA		75		µV/mA
V_{DO}	Dropout voltage(2) (V_{IN} = $V_{OUT(NOM)}$ – 0.1V)		I_{OUT} = 200mA		230	400	mV
I_{CL}	Output current limit (per output)		V_{OUT} = 0.9 × $V_{OUT(NOM)}$	240	340	575	mA
I_{GND}	Ground pin current		I_{OUT1} = I_{OUT2} = 0.1mA		90	160	µA
			I_{OUT1} = I_{OUT2} = 200mA		250		µA
I_{SHDN}	Shutdown current (I_{GND})		$V_{EN1,2}$ ≤ 0.4V, 2.7V ≤ V_{IN} < 4.5V, T_J = –40°C to +85°C		0.3	3.0	µA
			$V_{EN1,2}$ ≤ 0.4V, 4.5V ≤ V_{IN} ≤ 6.5V, T_J = –40°C to +85°C		1.8		µA
PSRR	Power-supply rejection ratio V_{IN} = 3.8V, V_{OUT} = 2.8V, I_{OUT} = 200mA		f = 100Hz		63		dB
			f = 1kHz		63		dB
			f = 10kHz		72		dB
			f = 100kHz		58		dB
			f = 1MHz		44		dB
V_N	Output noise voltage BW = 100Hz to 100kHz				70 × V_{OUT}		μV_{RMS}
T_{STR}	Startup time(3)		R_L = 14Ω, V_{OUT} = 2.8V, C_{OUT} = 1.0µF		160		µs
T_{SHUT}	Shutdown time(4), (5) (TPS719xx only)		R_L = ∞, C_{OUT} = 1.0µF, V_{OUT} = 2.8V		180		µs
$V_{EN(HI)}$	Enable high (enabled) (EN1 and EN2)		V_{IN} ≤ 5.5V	1.2		6.5	V
			5.5V < V_{IN} ≤ 6.5V	1.25		6.5	V
$V_{EN(LO)}$	Enable low (shutdown) (EN1 and EN2)			0		0.4	V
I_{EN}	Enable pin current, enabled (EN1 and EN2)		EN1 = EN2 = 6.5V		0.04	1.0	µA
UVLO	Undervoltage lockout		V_{IN} rising	2.38	2.45	2.52	V
	Hysteresis		V_{IN} falling		150		mV
T_{SD}	Thermal shutdown temperature		Shutdown, temperature increasing		+160		°C
			Reset, temperature decreasing		+140		°C
T_J	Operating junction temperature			–40		+125	°C

(1) Minimum V_{IN} = V_{OUT} + V_{DO} or 2.7V, whichever is greater.
(2) V_{DO} is not measured for devices with $V_{OUT(NOM)}$ < 2.8V because minimum V_{IN} = 2.7V.
(3) Time from V_{EN} = 1.25V to V_{OUT} = 95% ($V_{OUT(NOM)}$).
(4) Time from V_{EN} = 0.4V to V_{OUT} = 5% ($V_{OUT(NOM)}$).
(5) See *Shutdown* section in the Applications Information for more details.

DEVICE INFORMATION

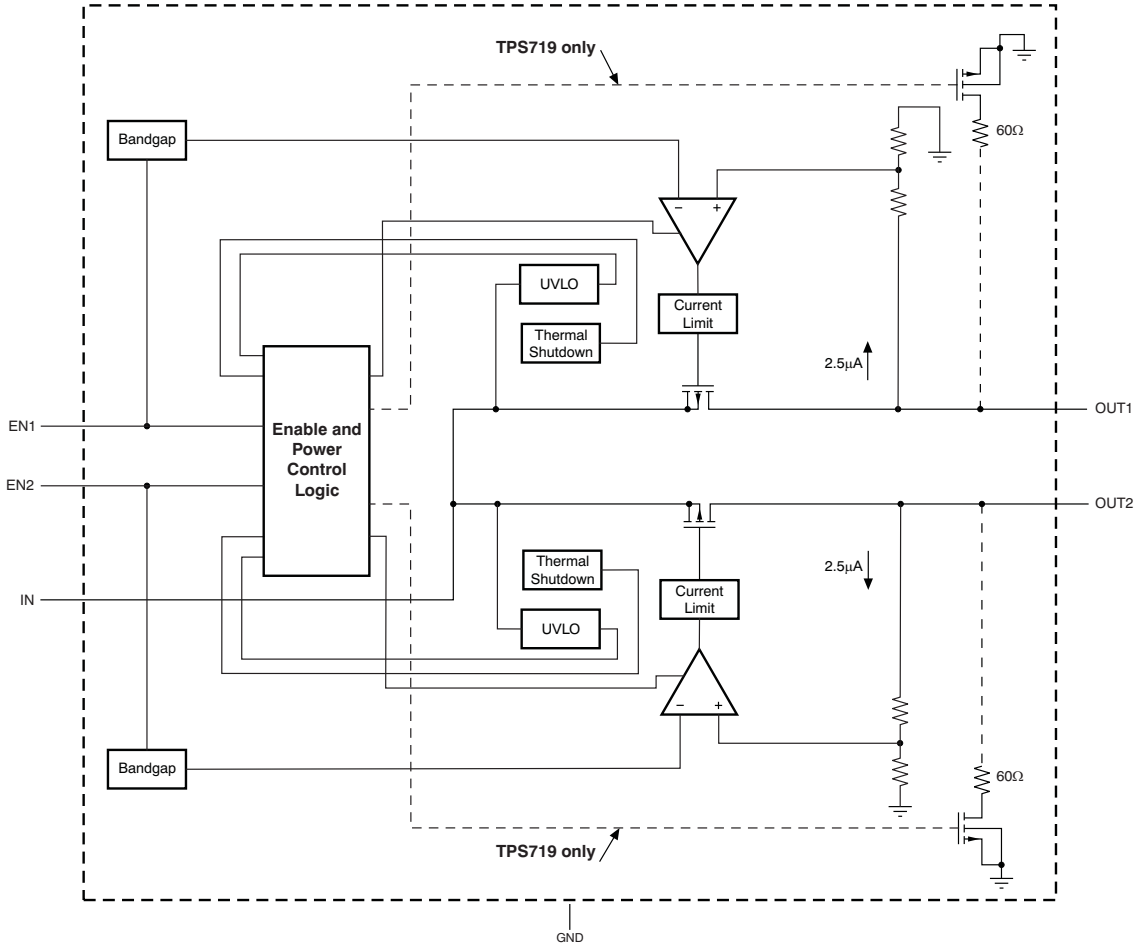
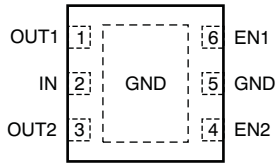
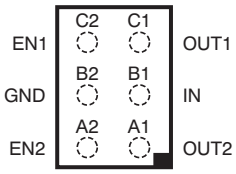


Figure 1. Functional Block Diagram

DRV PACKAGE
SON-6
(TOP VIEW)

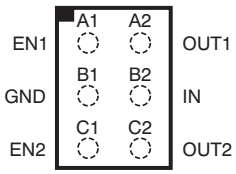


YZC PACKAGE
6-BALL WCSP
(TOP VIEW)



TPS718xx
TPS719xx

YZC PACKAGE
6-BALL WCSP
(TOP VIEW)



TPS718Axx
TPS719Axx

PIN DESCRIPTIONS

TPS718xx TPS719xx			TPS718Axx(1) TPS719Axx(1)	
NAME	**DRV**	**YZC**	**YZC**	**DESCRIPTION**
OUT1	1	C1	A2	Output of Regulator 1. A small ceramic capacitor (typically ≥ 1μF) is needed from this pin to ground to assure stability.
IN	2	B1	B2	Input supply to both regulators.
OUT2	3	A1	C2	Output of Regulator 2. A small ceramic capacitor (typically ≥ 1μF) is needed from this pin to ground to assure stability.
EN2	4	A2	C1	Enable pin for Regulator 2. Driving the Enable pin (EN2) high turns on Regulator 2. Driving this pin low puts Regulator 2 into shutdown mode, reducing operating current.
GND	5	B2	B1	Ground. DRV thermal pad should also be connected to ground.
EN1	6	C2	A1	Enable pin for Regulator 1. Driving the Enable pin (EN1) high turns on Regulator 1. Driving this pin low puts Regulator 1 into shutdown mode, reducing operating current.

(1) **A** option denotes devices with rotated Pin 1 orientation on Wafer Chipscale packages.

TYPICAL CHARACTERISTICS

Over operating temperature range (T_J = –40°C to +125°C), V_{IN} = $V_{OUT(TYP)}$ + 0.5V or 2.7V, whichever is greater; I_{OUT} = 0.5mA, V_{EN1} = V_{EN2} = V_{IN}, C_{OUT} = 1.0µF, unless otherwise noted. Typical values are at T_J = +25°C.

LINE REGULATION

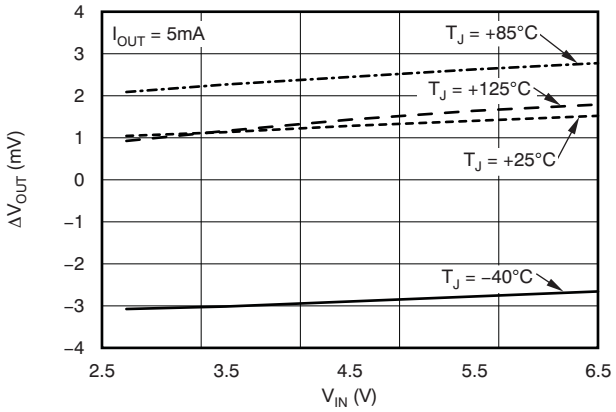


Figure 2.

LINE REGULATION

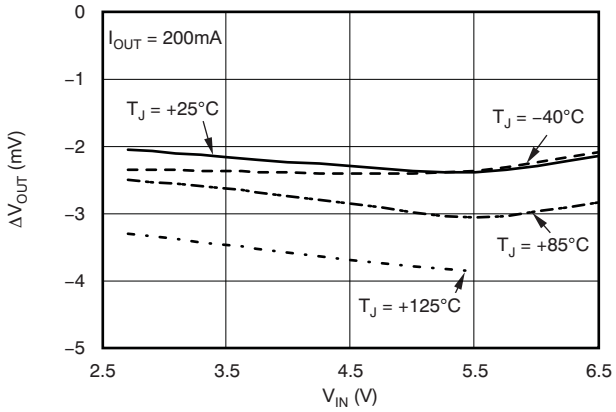


Figure 3.

LOAD REGULATION UNDER LIGHT LOADS

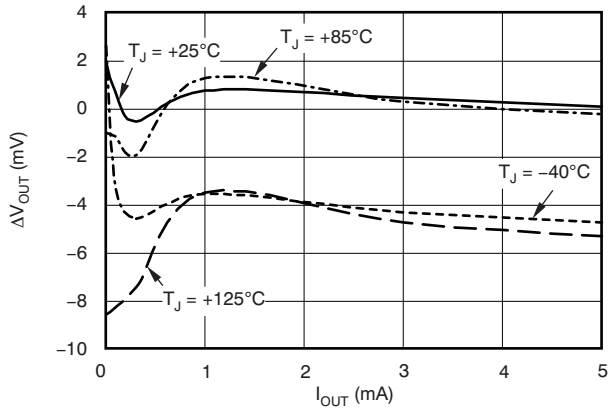


Figure 4.

LOAD REGULATION

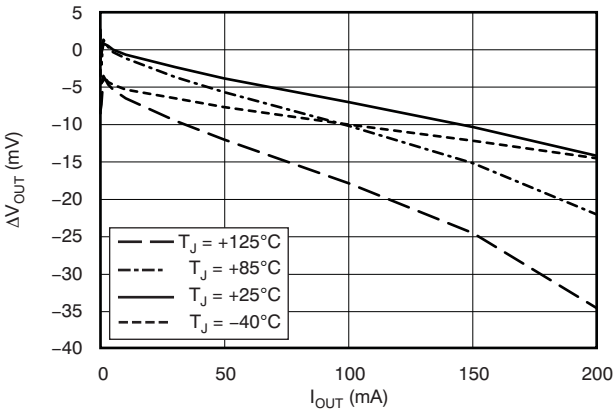


Figure 5.

OUTPUT VOLTAGE vs TEMPERATURE

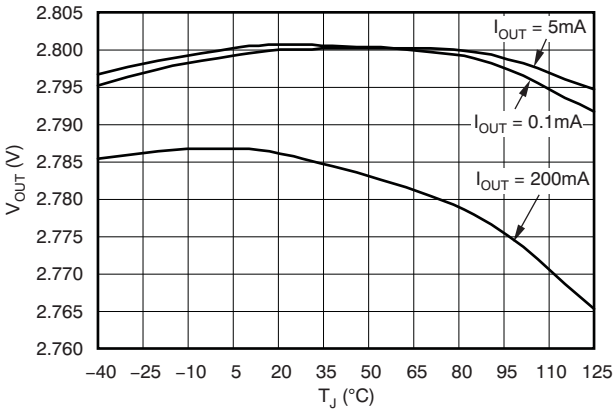


Figure 6.

DROPOUT VOLTAGE vs OUTPUT CURRENT

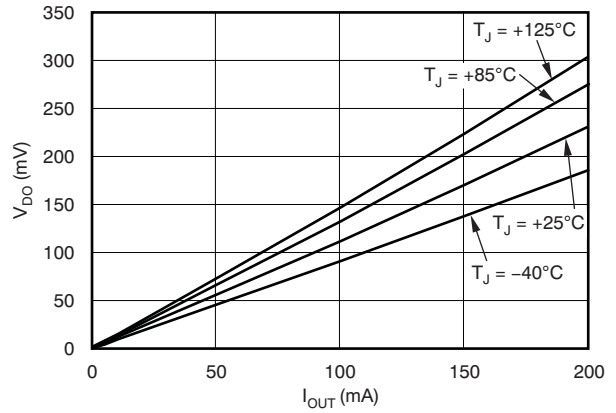


Figure 7.

TYPICAL CHARACTERISTICS (continued)

Over operating temperature range (T_J = –40°C to +125°C), V_{IN} = $V_{OUT(TYP)}$ + 0.5V or 2.7V, whichever is greater; I_{OUT} = 0.5mA, V_{EN1} = V_{EN2} = V_{IN}, C_{OUT} = 1.0µF, unless otherwise noted. Typical values are at T_J = +25°C.

GROUND PIN CURRENT vs OUTPUT CURRENT

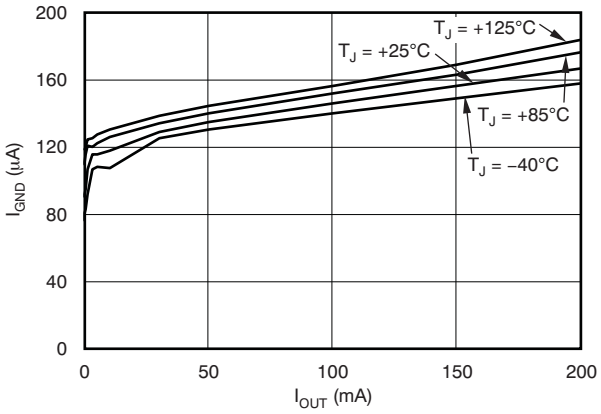


Figure 8.

GROUND PIN CURRENT vs INPUT VOLTAGE

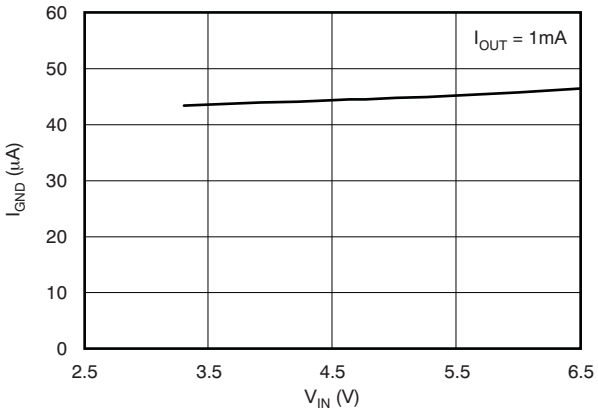


Figure 9.

GROUND PIN CURRENT vs TEMPERATURE (BOTH LDOs ENABLED)

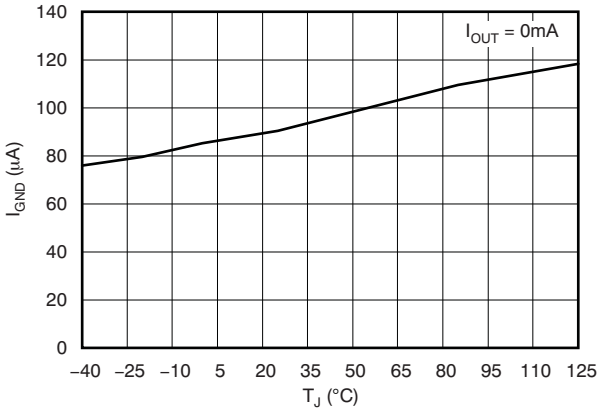


Figure 10.

SHUTDOWN CURRENT vs INPUT VOLTAGE

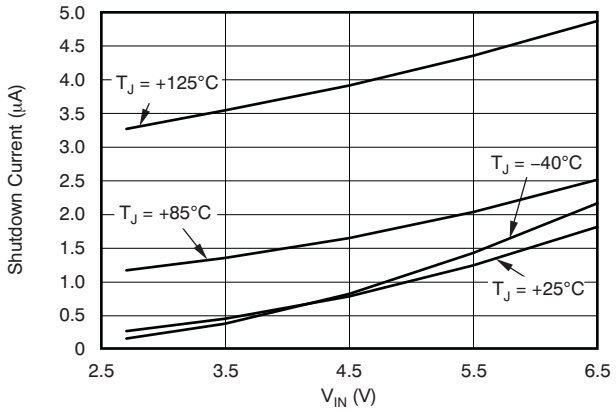


Figure 11.

CURRENT LIMIT vs INPUT VOLTAGE

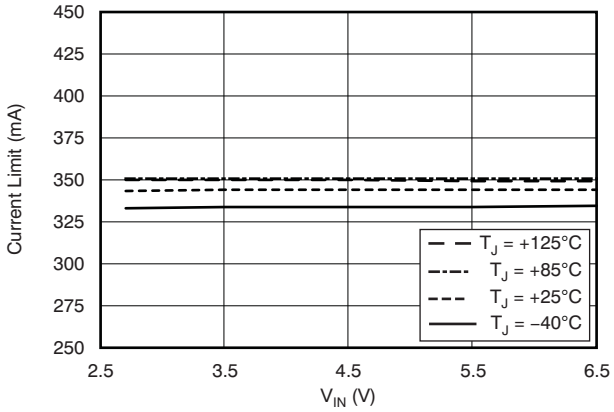


Figure 12.

POWER-SUPPLY RIPPLE REJECTION vs FREQUENCY (V_{IN} – V_{OUT} = 0.5V)

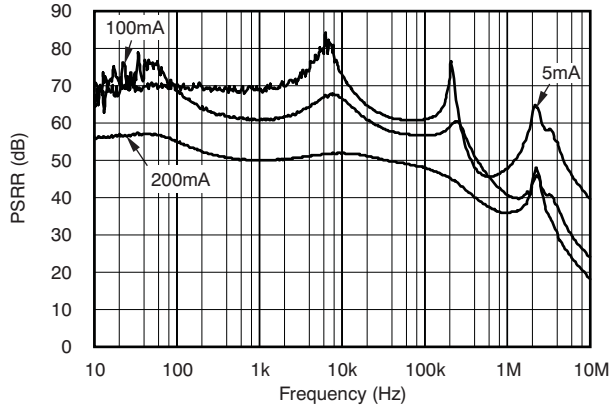


Figure 13.

TYPICAL CHARACTERISTICS (continued)

Over operating temperature range (T_J = –40°C to +125°C), V_{IN} = $V_{OUT(TYP)}$ + 0.5V or 2.7V, whichever is greater; I_{OUT} = 0.5mA, V_{EN1} = V_{EN2} = V_{IN}, C_{OUT} = 1.0µF, unless otherwise noted. Typical values are at T_J = +25°C.

POWER-SUPPLY RIPPLE REJECTION vs FREQUENCY (V_{IN} – V_{OUT} = 1V)

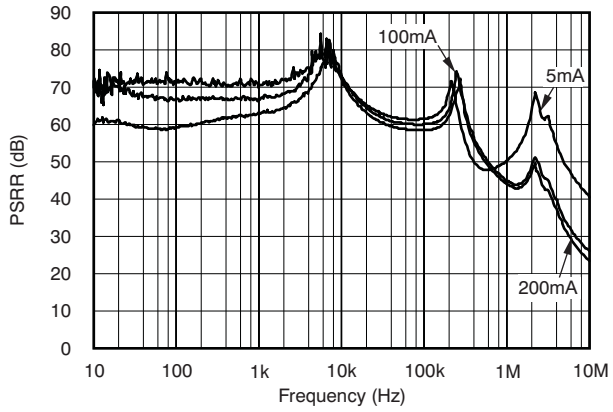


Figure 14.

POWER-SUPPLY RIPPLE REJECTION vs INPUT VOLTAGE

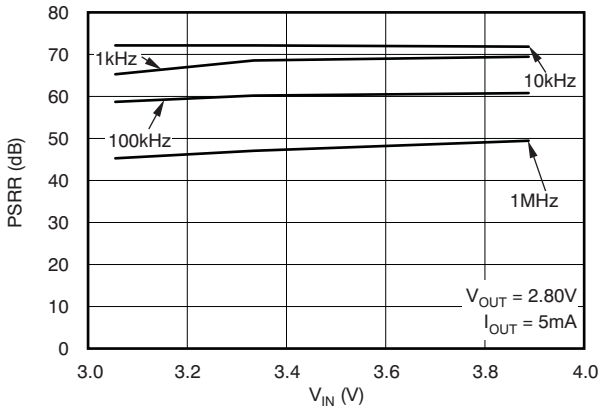


Figure 15.

POWER-SUPPLY RIPPLE REJECTION vs INPUT VOLTAGE

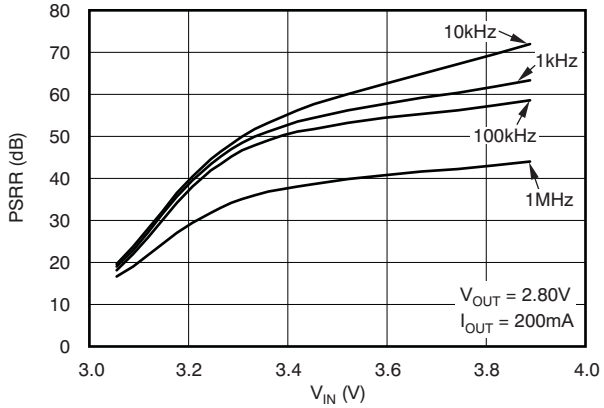


Figure 16.

OUTPUT SPECTRAL NOISE DENSITY vs FREQUENCY

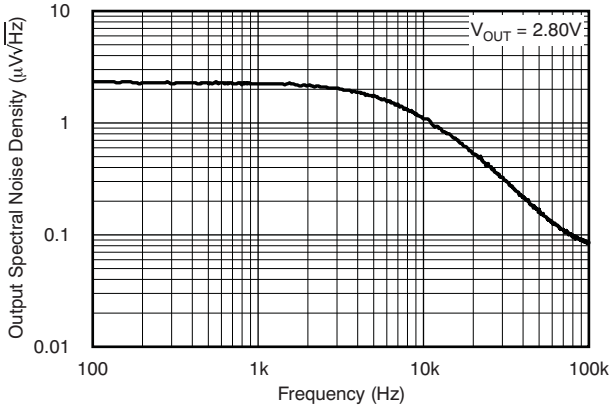


Figure 17.

LINE TRANSIENT RESPONSE

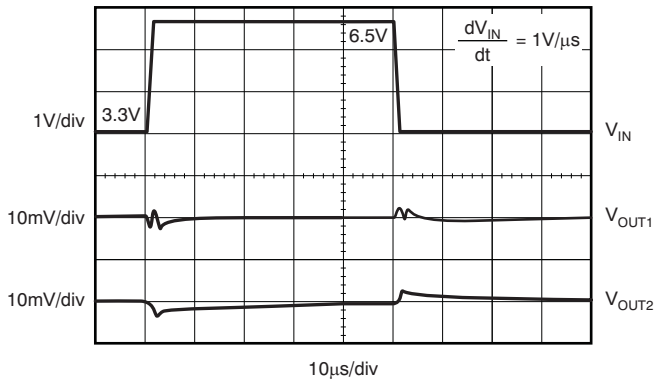


Figure 18.

LOAD TRANSIENT RESPONSE

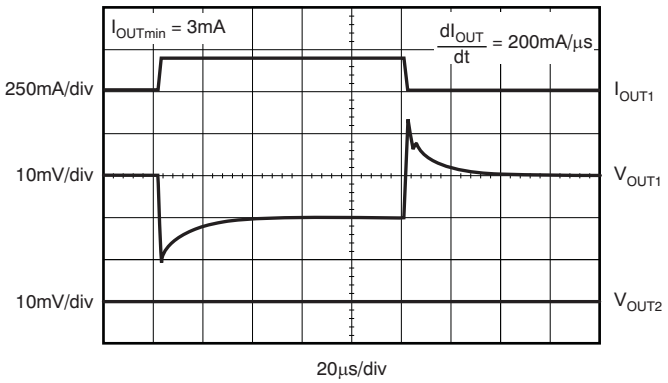


Figure 19.

TYPICAL CHARACTERISTICS (continued)

Over operating temperature range (T_J = –40°C to +125°C), V_{IN} = $V_{OUT(TYP)}$ + 0.5V or 2.7V, whichever is greater; I_{OUT} = 0.5mA, V_{EN1} = V_{EN2} = V_{IN}, C_{OUT} = 1.0µF, unless otherwise noted. Typical values are at T_J = +25°C.

TPS719 ENABLE RESPONSE

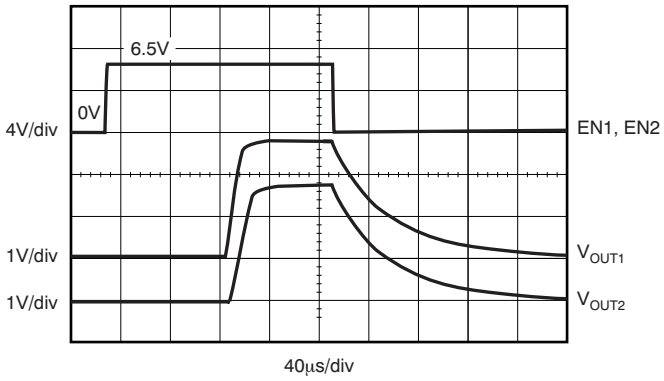


Figure 20.

POWER-UP/POWER-DOWN

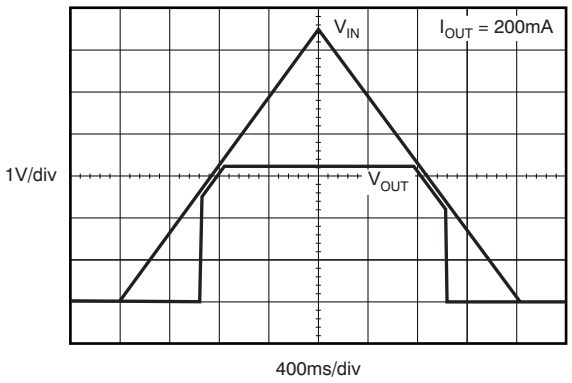


Figure 21.

APPLICATION INFORMATION

The TPS718xx/TPS719xx belong to a family of new generation LDO regulators that use innovative circuitry to achieve ultra-wide bandwidth and high loop gain, resulting in extremely high PSRR (up to 1MHz) at very low headroom (V_{IN} – V_{OUT}). These features, combined with low noise, two independent enables, low ground pin current and ultra-small packaging, make this part ideal for portable applications. This family of regulators offer sub-bandgap output voltages, current limit and thermal protection, and is fully specified from –40°C to +125°C.

Figure 22 shows the basic circuit connections.

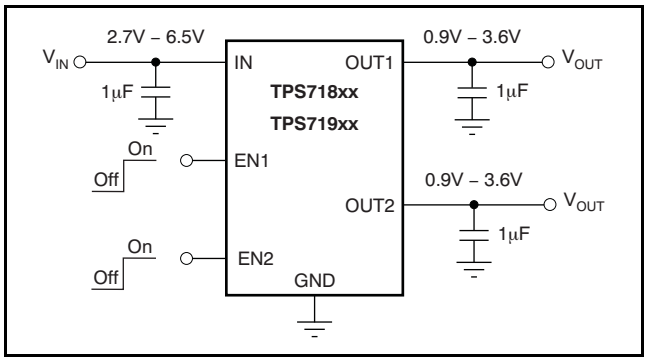


Figure 22. Typical Application Circuit

Input and Output Capacitor Requirements

Although an input capacitor is not required for stability, it is good analog design practice to connect a 0.1µF to 1.0µF low equivalent series resistance (ESR) capacitor across the input supply near the regulator. This capacitor counteracts reactive input sources and improves transient response, noise rejection, and ripple rejection. A higher-value capacitor may be necessary if large, fast rise-time load transients are anticipated or if the device is located close to the power source. If source impedance is not sufficiently low, a 0.1µF input capacitor may be necessary to ensure stability.

The TPS718xx/TPS719xx are designed to be stable with standard ceramic capacitors of values 1.0µF or larger at the output. X5R- and X7R-type capacitors are best because they have minimal variation in value and ESR over temperature. Maximum ESR should be <1.0Ω.

Board Layout Recommendations to Improve PSRR and Noise Performance

To improve ac performance such as PSRR, output noise, and transient response, it is recommended that the board be designed with separate ground planes for V_{IN} and V_{OUT}, with each ground plane connected only at the GND pin of the device. In addition, the ground connection for the output capacitor should connect directly to the GND pin of the device. High ESR capacitors may degrade PSRR.

Internal Current Limit

The TPS718xx/TPS719xx internal current limits help protect the regulator during fault conditions. During current limit, the output sources a fixed amount of current that is largely independent of output voltage. For reliable operation, the device should not be operated in a current limit state for extended periods of time.

The PMOS pass element in the TPS718xx/TPS719xx has a built-in body diode that conducts current when the voltage at OUT exceeds the voltage at IN. This current is not limited, so if extended reverse voltage operation is anticipated, external limiting to 5% of rated output current may be appropriate.

Shutdown

The enable pin (EN) is active high and is compatible with standard and low voltage, TTL-CMOS levels. When shutdown capability is not required, EN can be connected to IN. The TPS719 with internal active output pulldown circuitry discharges the output with a time constant (*t*) of:

$$t = 3\left(\frac{60 \times R_L}{60 + R_L}\right) \times C_{OUT}$$

with:

R_L = output load resistance

C_{OUT} = output capacitance

Dropout Voltage

The TPS718xx/TPS719xx use a PMOS pass transistor to achieve low dropout. When (V_{IN} – V_{OUT}) is less than the dropout voltage (V_{DO}), the PMOS pass device is in its linear region of operation and the input-to-output resistance is the $R_{DS(ON)}$ of the PMOS pass element. V_{DO} approximately scales with output current because the PMOS device behaves like a resistor in dropout.

As with any linear regulator, PSRR and transient response are degraded as (V_{IN} – V_{OUT}) approaches dropout. This effect is shown in Figure 13 and Figure 14 in the Typical Characteristics section.

Transient Response

As with any regulator, increasing the size of the output capacitor will reduce over/undershoot magnitude but increase duration of the transient response.

Undervoltage Lock-Out (UVLO)

The TPS718xx/TPS719xx utilize an undervoltage lock-out circuit to keep the output shut off until internal circuitry is operating properly. The UVLO circuit has a de-glitch feature so that it typically ignores undershoot transients on the input if they are less than 50μs duration. On the TPS719xx, the active pulldown discharges V_{OUT} when the device is in UVLO off condition. However, the input voltage needs to be greater than 0.8V for active pulldown to work.

Minimum Load

The TPS718xx/TPS719xx are stable with no output load. Traditional PMOS LDO regulators suffer from lower loop gain at very light output loads. The TPS718xx/TPS719xx employ an innovative, low-current mode circuit under very light or no-load conditions, resulting in improved output voltage regulation performance down to zero output current.

THERMAL INFORMATION

Thermal Protection

Thermal protection disables the output when the junction temperature rises to approximately +160°C, allowing the device to cool. When the junction temperature cools to approximately +140°C the output circuitry is again enabled. Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit may cycle on and off. This cycling limits the dissipation of the regulator, protecting it from damage due to overheating.

Any tendency to activate the thermal protection circuit indicates excessive power dissipation or an inadequate heatsink. For reliable operation, junction temperature should be limited to +125°C maximum. To estimate the margin of safety in a complete design (including heatsink), increase the ambient temperature until the thermal protection is triggered; use worst-case loads and signal conditions. For good reliability, thermal protection should trigger at least +35°C above the maximum expected ambient condition of your particular application. This configuration produces a worst-case junction temperature of +125°C at the highest expected ambient temperature and worst-case load.

The internal protection circuitry of the TPS718xx/TPS719xx has been designed to protect against overload conditions. It was not intended to replace proper heatsinking. Continuously running the TPS718xx/TPS719xx into thermal shutdown degrades device reliability.

Power Dissipation

The ability to remove heat from the die is different for each package type, presenting different considerations in the printed circuit board (PCB) layout. The PCB area around the device that is free of other components moves the heat from the device to the ambient air. Performance data for JEDEC low- and high-K boards are given in the *Dissipation Ratings* table. Using heavier copper increases the effectiveness in removing heat from the device. The addition of plated through-holes to heat-dissipating layers also improves the heatsink effectiveness.

Power dissipation depends on input voltage and load conditions. Power dissipation (P_D) is equal to the product of the output current times the voltage drop across the output pass element (V_{IN} to V_{OUT}), as shown in Equation 1:

$$P_D = (V_{IN} - V_{OUT}) \times I_{OUT} \quad (1)$$

Package Mounting

Solder pad footprint recommendations for the TPS718xx/TPS719xxx are available from the Texas Instruments web site at www.ti.com.

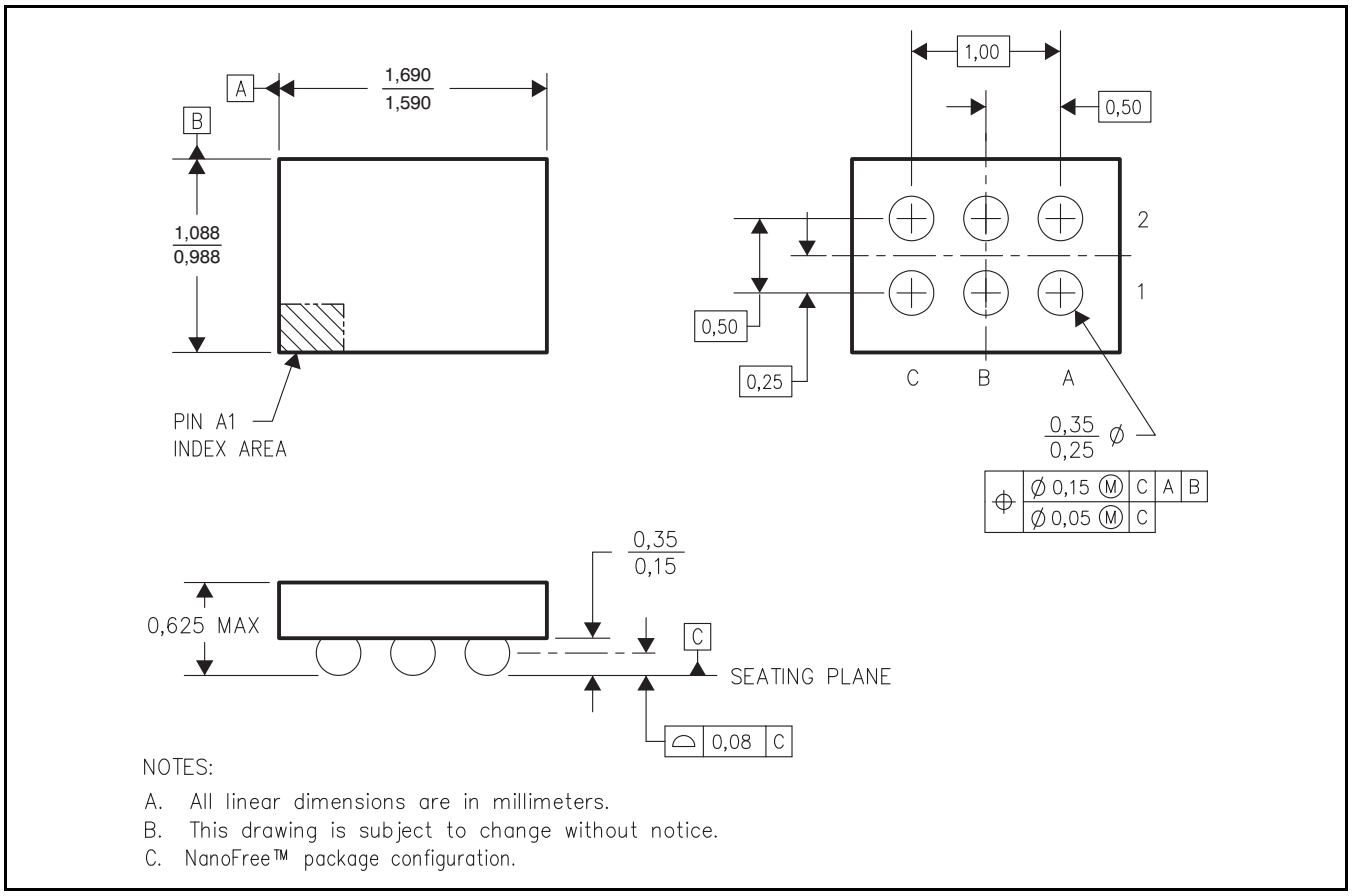


Figure 23. YZC Wafer Chip-Scale Package Dimensions (in mm)

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS71812-33DRVR	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	BVC	Samples
TPS71812-33DRVT	ACTIVE	WSON	DRV	6	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	BVC	Samples
TPS71818-33DRVR	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	OEI	Samples
TPS71818-33DRVT	ACTIVE	WSON	DRV	6	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	OEI	Samples
TPS71825-12DRVR	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	BVO	Samples
TPS71825-12DRVT	ACTIVE	WSON	DRV	6	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	BVO	Samples
TPS71828-30DRVR	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	BVX	Samples
TPS71828-30DRVT	ACTIVE	WSON	DRV	6	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	BVX	Samples
TPS71913-28DRVR	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	BWP	Samples
TPS71913-28DRVT	ACTIVE	WSON	DRV	6	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	BWP	Samples
TPS71918-12DRVR	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	BWW	Samples
TPS71918-12DRVT	ACTIVE	WSON	DRV	6	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	BWW	Samples
TPS71918-28DRVR	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	NIPDAU | NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	ODQ	Samples
TPS71918-28DRVT	ACTIVE	WSON	DRV	6	250	Green (RoHS & no Sb/Br)	NIPDAU | NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	ODQ	Samples
TPS71921-22DRVR	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	OBW	Samples
TPS71921-22DRVT	ACTIVE	WSON	DRV	6	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	OBW	Samples
TPS71928-28DRVR	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CAK	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS71928-28DRVT	ACTIVE	WSON	DRV	6	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CAK	Samples
TPS71928-28DRVTG4	ACTIVE	WSON	DRV	6	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CAK	Samples
TPS719285-285DRVR	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	OAU	Samples
TPS71933-28DRVR	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CAH	Samples
TPS71933-28DRVT	ACTIVE	WSON	DRV	6	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CAH	Samples
TPS71933-28DRVTG4	ACTIVE	WSON	DRV	6	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CAH	Samples
TPS71933-33DRVR	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	BWL	Samples
TPS71933-33DRVT	ACTIVE	WSON	DRV	6	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	BWL	Samples
TPS71936-315DRVR	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CVZ	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

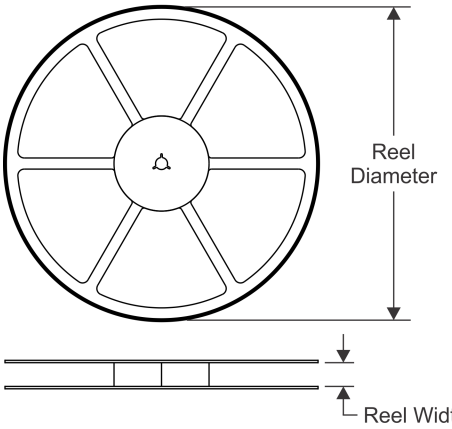
(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

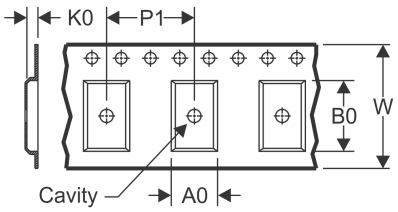
(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

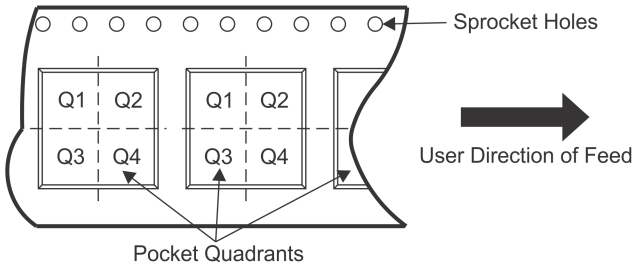


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

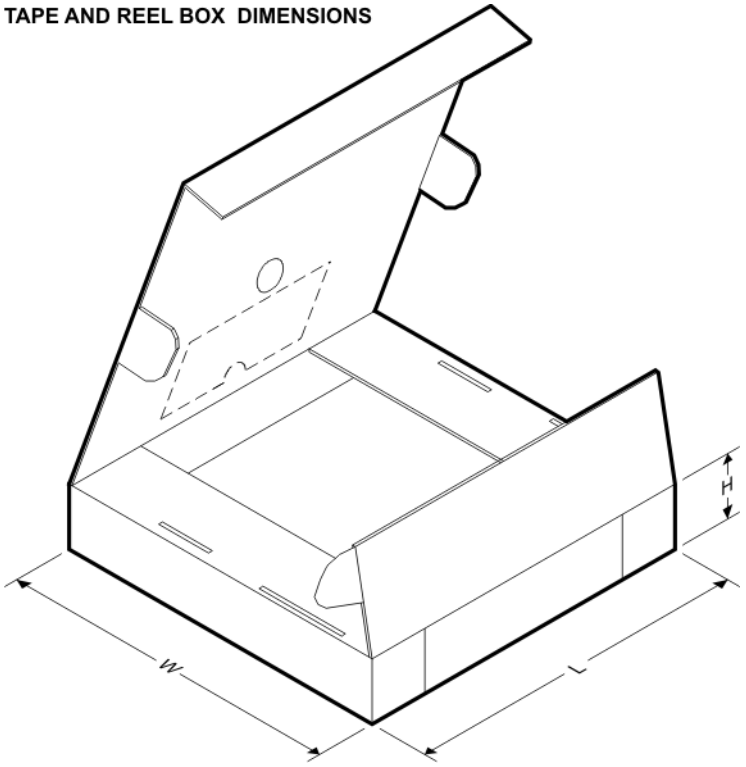


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS71812-33DRVR	WSON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71812-33DRVT	WSON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71818-33DRVR	WSON	DRV	6	3000	178.0	8.4	2.25	2.25	1.0	4.0	8.0	Q2
TPS71818-33DRVT	WSON	DRV	6	250	178.0	8.4	2.25	2.25	1.0	4.0	8.0	Q2
TPS71825-12DRVR	WSON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71825-12DRVT	WSON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71828-30DRVR	WSON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71828-30DRVT	WSON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71913-28DRVR	WSON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71913-28DRVT	WSON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71918-12DRVR	WSON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71918-12DRVT	WSON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71918-28DRVR	WSON	DRV	6	3000	178.0	8.4	2.25	2.25	1.0	4.0	8.0	Q2
TPS71918-28DRVT	WSON	DRV	6	250	178.0	8.4	2.25	2.25	1.0	4.0	8.0	Q2
TPS71921-22DRVR	WSON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71921-22DRVT	WSON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71928-28DRVR	WSON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71928-28DRVT	WSON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS719285-285DRVR	WSON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71933-28DRVR	WSON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71933-28DRVT	WSON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71933-33DRVR	WSON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71933-33DRVT	WSON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71936-315DRVR	WSON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2

TAPE AND REEL BOX DIMENSIONS



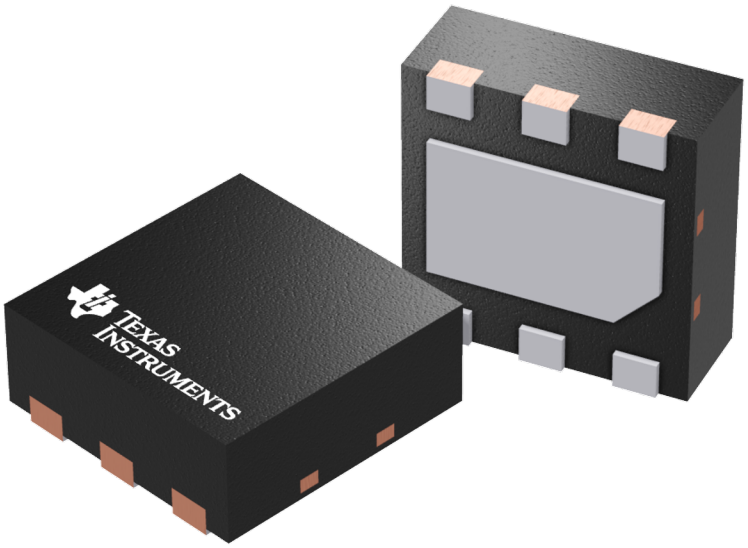
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS71812-33DRVR	WSON	DRV	6	3000	203.0	203.0	35.0
TPS71812-33DRVT	WSON	DRV	6	250	203.0	203.0	35.0
TPS71818-33DRVR	WSON	DRV	6	3000	205.0	200.0	33.0
TPS71818-33DRVT	WSON	DRV	6	250	205.0	200.0	33.0
TPS71825-12DRVR	WSON	DRV	6	3000	203.0	203.0	35.0
TPS71825-12DRVT	WSON	DRV	6	250	203.0	203.0	35.0
TPS71828-30DRVR	WSON	DRV	6	3000	203.0	203.0	35.0
TPS71828-30DRVT	WSON	DRV	6	250	203.0	203.0	35.0
TPS71913-28DRVR	WSON	DRV	6	3000	203.0	203.0	35.0
TPS71913-28DRVT	WSON	DRV	6	250	203.0	203.0	35.0
TPS71918-12DRVR	WSON	DRV	6	3000	203.0	203.0	35.0

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS71918-12DRVT	WSON	DRV	6	250	203.0	203.0	35.0
TPS71918-28DRVR	WSON	DRV	6	3000	205.0	200.0	33.0
TPS71918-28DRVT	WSON	DRV	6	250	205.0	200.0	33.0
TPS71921-22DRVR	WSON	DRV	6	3000	203.0	203.0	35.0
TPS71921-22DRVT	WSON	DRV	6	250	203.0	203.0	35.0
TPS71928-28DRVR	WSON	DRV	6	3000	203.0	203.0	35.0
TPS71928-28DRVT	WSON	DRV	6	250	203.0	203.0	35.0
TPS719285-285DRVR	WSON	DRV	6	3000	203.0	203.0	35.0
TPS71933-28DRVR	WSON	DRV	6	3000	203.0	203.0	35.0
TPS71933-28DRVT	WSON	DRV	6	250	203.0	203.0	35.0
TPS71933-33DRVR	WSON	DRV	6	3000	203.0	203.0	35.0
TPS71933-33DRVT	WSON	DRV	6	250	203.0	203.0	35.0
TPS71936-315DRVR	WSON	DRV	6	3000	203.0	203.0	35.0

DRV 6 WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



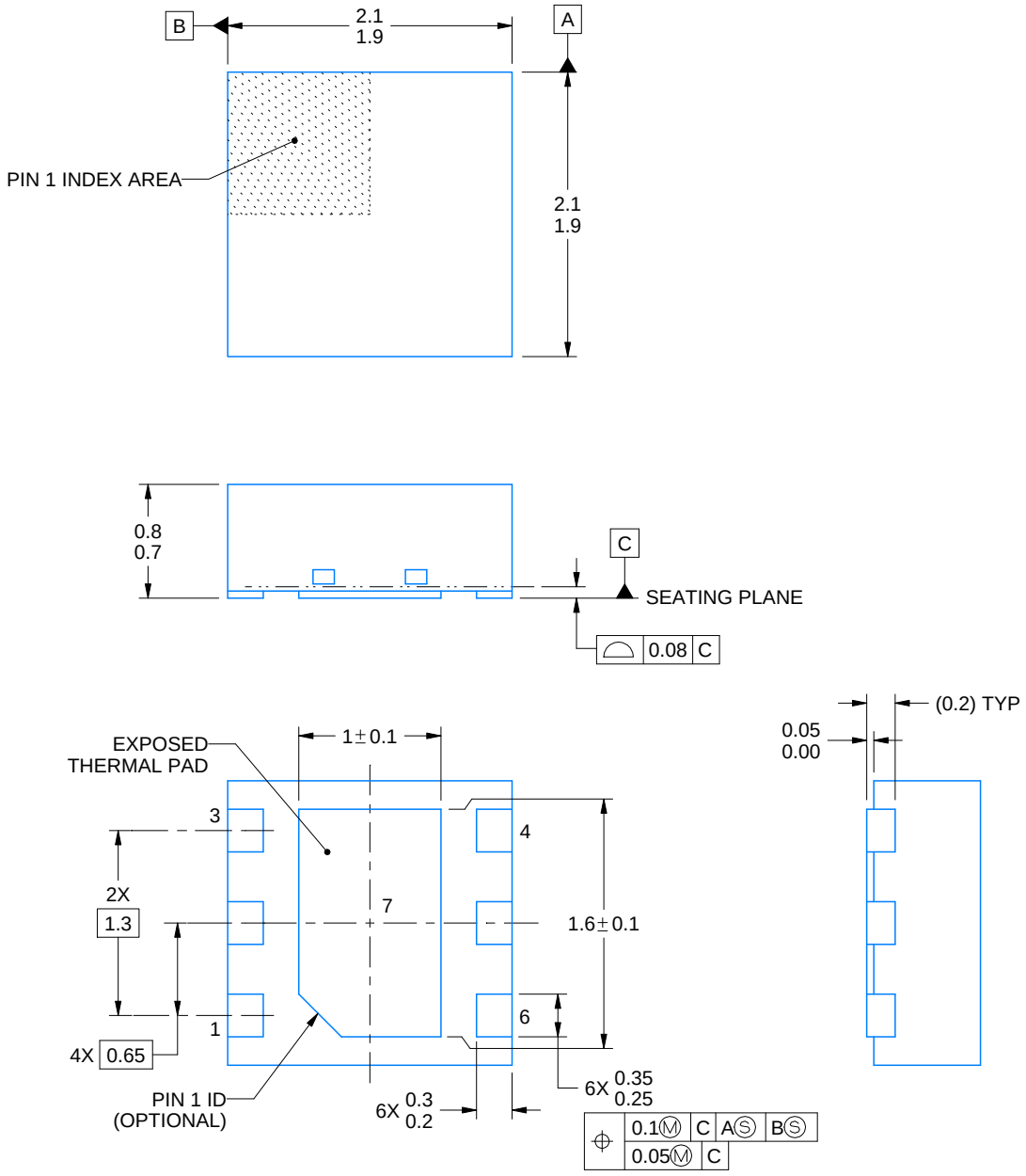
Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

PACKAGE OUTLINE

DRV0006A

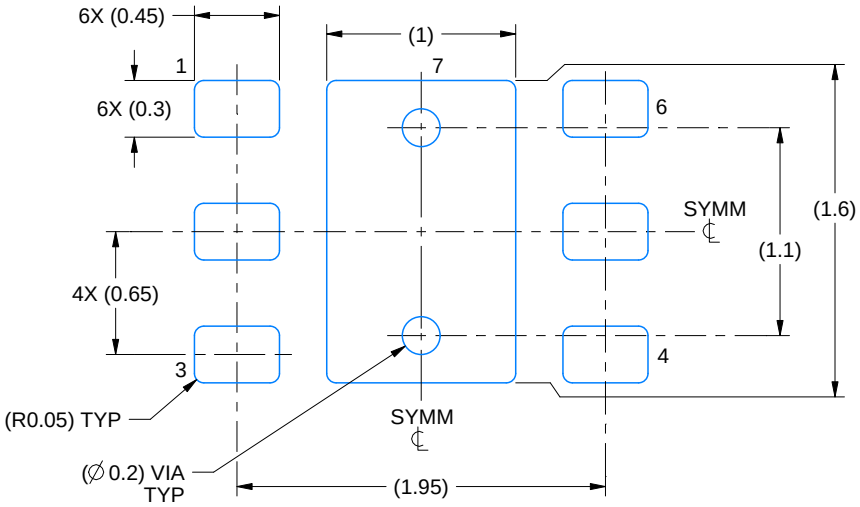
WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD

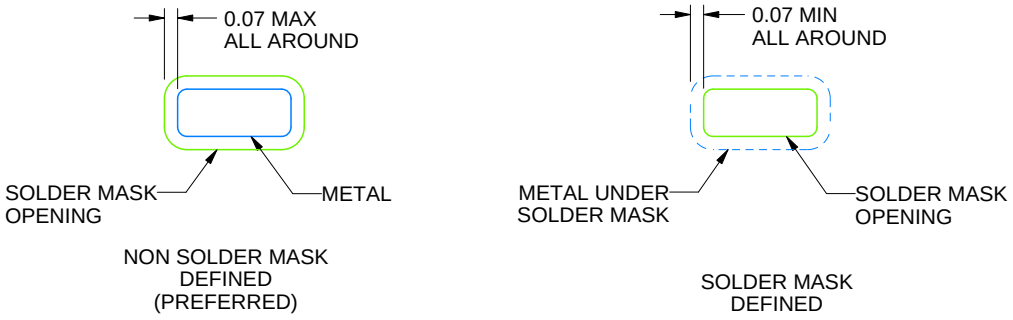


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



LAND PATTERN EXAMPLE
SCALE:25X



SOLDER MASK DETAILS

4222173/B 04/2018

NOTES: (continued)

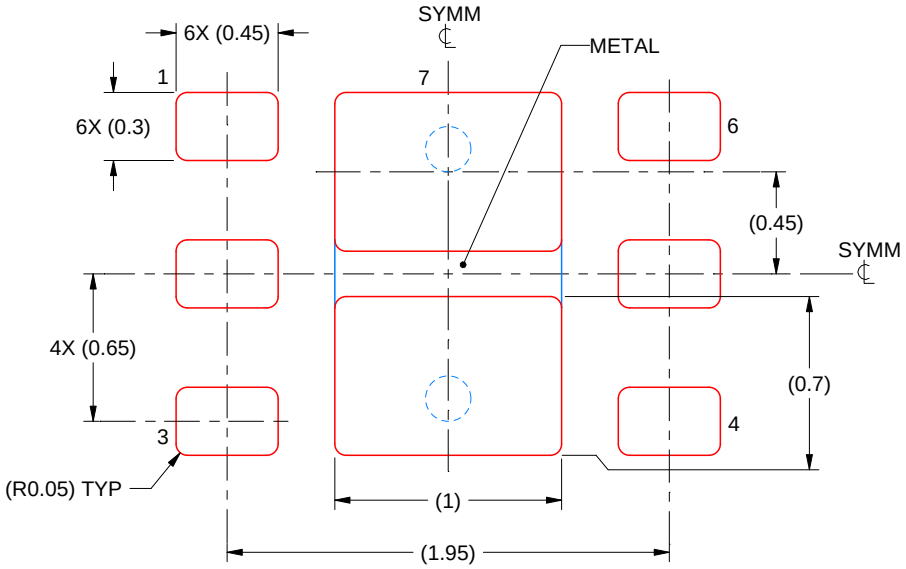
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.

EXAMPLE STENCIL DESIGN

DRV0006A

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD #7
88% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:30X

4222173/B 04/2018

NOTES: (continued)

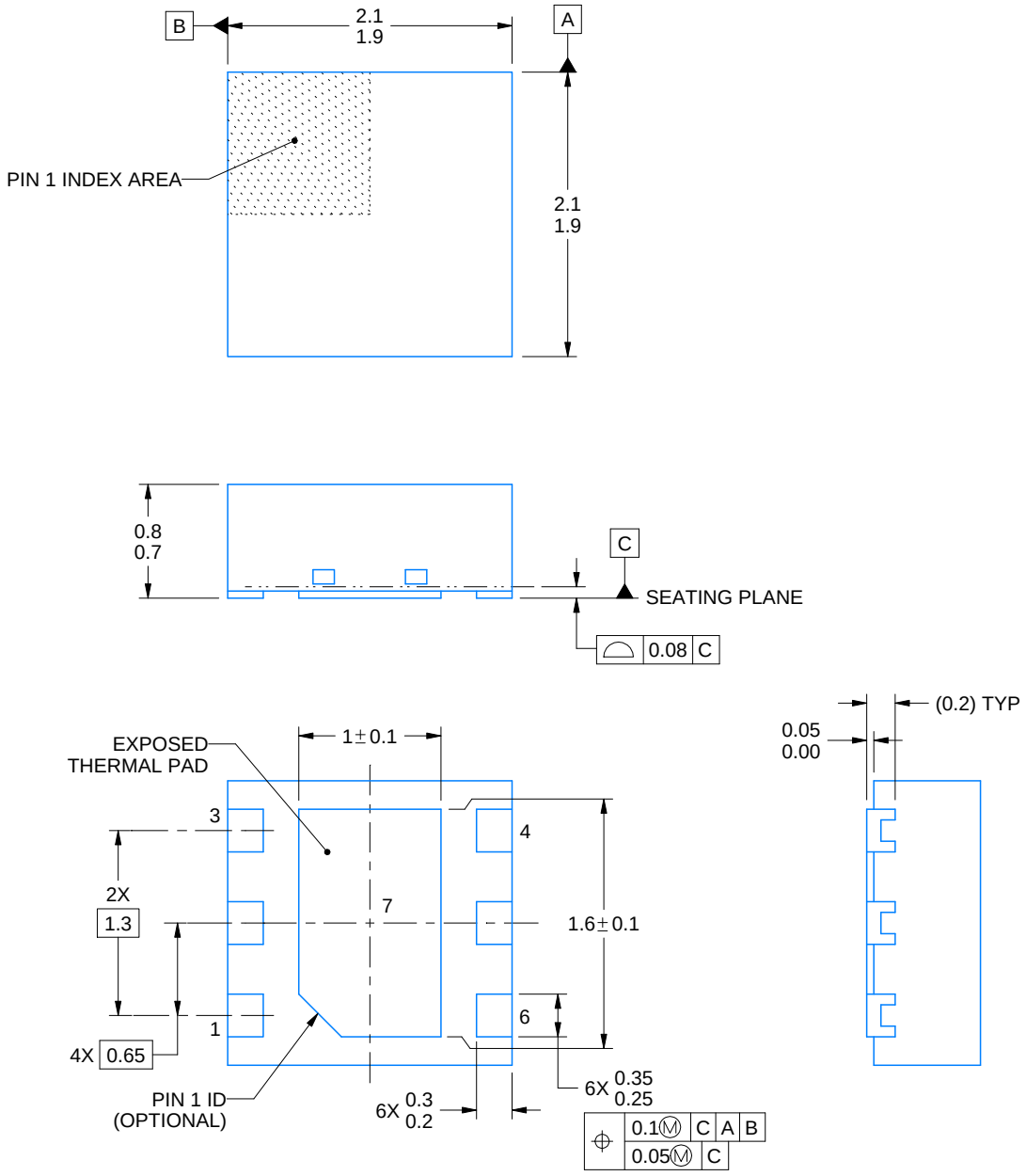
6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

DRV0006D

PACKAGE OUTLINE

WSON - 0.8 mm max height

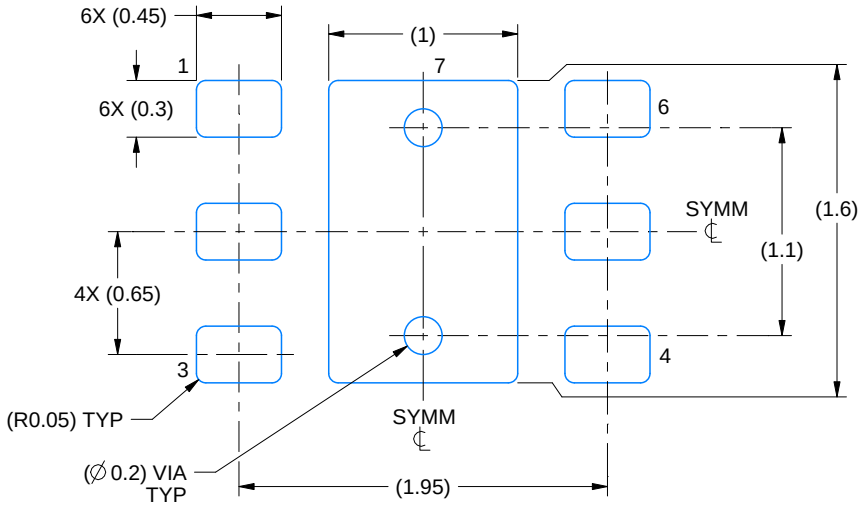
PLASTIC SMALL OUTLINE - NO LEAD



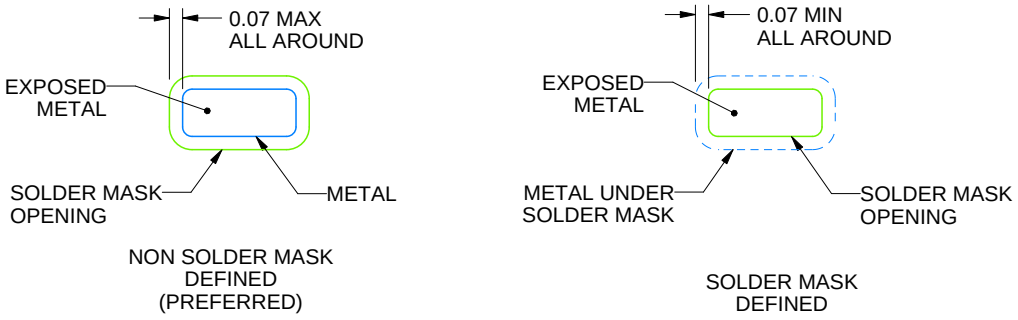
4225563/A 12/2019

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:25X

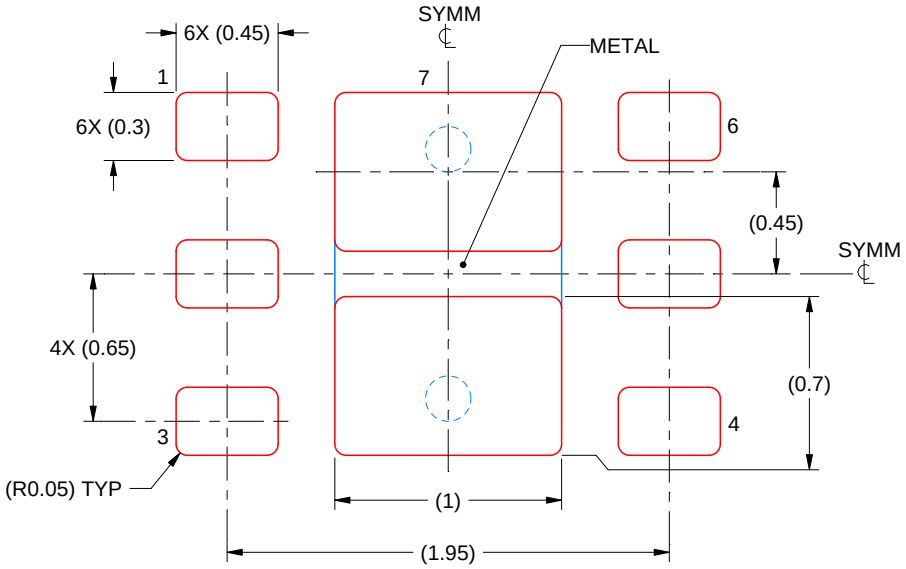


SOLDER MASK DETAILS

4225563/A 12/2019

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD #7
88% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:30X

4225563/A 12/2019

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES “AS IS” AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI’s products are provided subject to TI’s Terms of Sale (www.ti.com/legal/termsofsale.html) or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI’s provision of these resources does not expand or otherwise alter TI’s applicable warranties or warranty disclaimers for TI products.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265